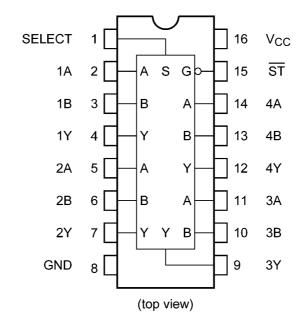
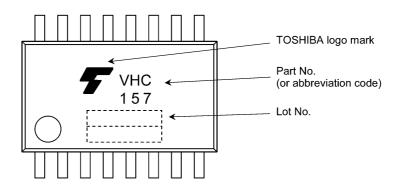


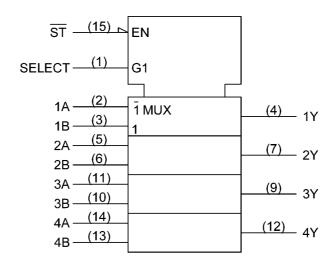
#### 5. Pin Assignment



#### 6. Marking



#### 7. IEC Logic Symbol



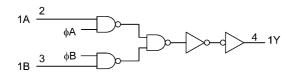


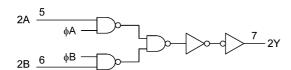
### 8. Truth Table

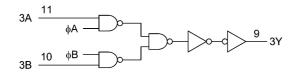
Inputs ST	Inputs SELECT	Inputs A	Inputs B	Output Y
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	Н	X	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

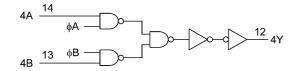
X: Don't care

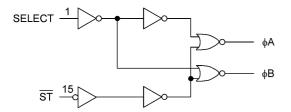
### 9. System Diagram













#### 10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V <sub>CC</sub>		-0.5 to 7.0	V
Input voltage	V <sub>IN</sub>		-0.5 to 7.0	V
Output voltage	V <sub>OUT</sub>		-0.5 to V <sub>CC</sub> + 0.5	V
Input diode current	I <sub>IK</sub>		-20	mA
Output diode current	I <sub>OK</sub>		±20	mA
Output current	I <sub>OUT</sub>		±25	mA
V <sub>CC</sub> /ground current	Icc		±50	mA
Power dissipation	P <sub>D</sub>	(Note 1)	180	mW
Storage temperature	T <sub>stg</sub>		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of  $T_a$  = -40 to 85 °C. From  $T_a$  = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

#### 11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V <sub>CC</sub>		2.0 to 5.5	V
Input voltage	V <sub>IN</sub>		0 to 5.5	V
Output voltage	V <sub>OUT</sub>		0 to V <sub>CC</sub>	V
Operating temperature	T <sub>opr</sub>		-40 to 125	°C
Input rise and fall times	dt/dv	$V_{CC}$ = 3.3 ± 0.3 V	0 to 100	ns/V
		$V_{CC} = 5 \pm 0.5 \text{ V}$	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either  $V_{CC}$  or GND.



#### 12. Electrical Characteristics

# 12.1. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Тур.	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_		0.50	V
				3.0 to 5.5	_		$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -50 μA	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I <sub>OH</sub> = -4 mA	3.0	2.58	_	_	
			I <sub>OH</sub> = -8 mA	4.5	3.94		_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I <sub>OL</sub> = 4 mA	3.0	_	_	0.36	
			I <sub>OL</sub> = 8 mA	4.5	_		0.36	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	_	±0.1	μΑ
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	

### 12.2. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 85 °C)

Characteristics	Symbol	Test Condition		V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	V
				3.0 to 5.5		$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH}$ = -4 mA	3.0	2.48	_	
			$I_{OH}$ = -8 mA	4.5	3.80	_	
Low-level output voltage	V <sub>OL</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OL</sub> = 50 μA	2.0		0.1	V
				3.0		0.1	
				4.5	_	0.1	
			$I_{OL}$ = 4 mA	3.0	_	0.44	
			I <sub>OL</sub> = 8 mA	4.5		0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±1.0	μА
Quiescent supply current	I <sub>CC</sub>	$V_{IN} = V_{CC}$ or GND		5.5	_	40.0	μА



### 12.3. DC Characteristics (Unless otherwise specified, T<sub>a</sub> = -40 to 125 °C)

Characteristics	Symbol	Test Cond	dition	V <sub>CC</sub> (V)	Min	Max	Unit
High-level input voltage	V <sub>IH</sub>	_		2.0	1.50	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V <sub>IL</sub>	_		2.0	_	0.50	٧
				3.0 to 5.5	_	$V_{CC} \times 0.3$	
High-level output voltage	V <sub>OH</sub>	$V_{IN} = V_{IH}$ or $V_{IL}$	I <sub>OH</sub> = -50 μA	2.0	1.9	_	٧
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.40	_	
			$I_{OH}$ = -8 mA	4.5	3.70	_	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OL</sub> = 50 μA	2.0	_	0.1	٧
				3.0	_	0.1	
				4.5	_	0.1	
			$I_{OL}$ = 4 mA	3.0	_	0.55	
			I <sub>OL</sub> = 8 mA	4.5	_	0.55	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = 5.5 V or GND		0 to 5.5	_	±2.0	μА
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	_	80.0	μΑ

### 12.4. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Тур.	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$3.3\pm0.3$	15	_	6.2	9.7	ns
(A, B - Y)				50	-	8.7	13.2	
			$5.0 \pm 0.5$	15	ı	4.1	6.4	
				50		5.6	8.4	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$3.3 \pm 0.3$	15	I	8.4	13.2	ns
(SELECT - Y)				50		10.9	16.7	
			$5.0 \pm 0.5$	15		5.3	8.1	
				50		6.8	10.1	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>		$3.3 \pm 0.3$	15	I	8.7	13.6	ns
( <del>ST</del> - Y)				50		11.2	17.1	
			$5.0 \pm 0.5$	15	-	5.6	8.6	
				50	_	7.1	10.6	
Input capacitance	C <sub>IN</sub>					4	10	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note 1)		·	_	20	_	pF

Note 1: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

 $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC} / 4 \text{ (per bit)}$ 



# 12.5. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$3.3 \pm 0.3$	15	1.0	11.5	ns
(A, B - Y)			50	1.0	15.0	
		$5.0 \pm 0.5$	15	1.0	7.5	
			50	1.0	9.5	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$3.3 \pm 0.3$	15	1.0	15.5	ns
(SELECT - Y)			50	1.0	19.0	
		$5.0 \pm 0.5$	15	1.0	9.5	
			50	1.0	11.5	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	3.3 ± 0.3	15	1.0	16.0	ns
(ST - Y)			50	1.0	19.5	
		5.0 ± 0.5	15	1.0	10.0	
			50	1.0	12.0	
Input capacitance	C <sub>IN</sub>				10	pF

# 12.6. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 3$ ns)

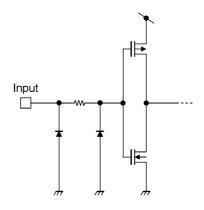
Characteristics	Symbol	V <sub>CC</sub> (V)	C <sub>L</sub> (pF)	Min	Max	Unit
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$3.3 \pm 0.3$	15	1.0	13.0	ns
(A, B - Y)			50	1.0	16.5	
		5.0 ± 0.5	15	1.0	8.5	
			50	1.0	10.5	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$3.3 \pm 0.3$	15	1.0	17.5	ns
(SELECT - Y)			50	1.0	21.0	
		5.0 ± 0.5	15	1.0	11.0	
			50	1.0	13.0	
Propagation delay time	t <sub>PLH</sub> ,t <sub>PHL</sub>	$3.3 \pm 0.3$	15	1.0	18.0	ns
( <del>ST</del> - Y)			50	1.0	21.5	
		5.0 ± 0.5	15	1.0	11.5	
			50	1.0	13.5	
Input capacitance	C <sub>IN</sub>			_	10	pF

# 12.7. Noise Characteristics (Unless otherwise specified, $T_a$ = 25 °C, Input: $t_f$ = $t_f$ = 3 ns)

Characteristics	Symbol	Test Condition	V <sub>CC</sub> (V)	Тур.	Limit	Unit
Quiet output maximum dynamic V <sub>OL</sub>	V <sub>OLP</sub>	C <sub>L</sub> = 50 pF	5.0	0.3	0.8	V
Quiet output minimum dynamic V <sub>OL</sub>	V <sub>OLV</sub>	C <sub>L</sub> = 50 pF	5.0	-0.3	-0.8	V
Minimum high-level dynamic input voltage	$V_{IHD}$	C <sub>L</sub> = 50 pF	5.0		3.5	V
Maximum low-level dynamic input voltage	$V_{ILD}$	C <sub>L</sub> = 50 pF	5.0		1.5	V

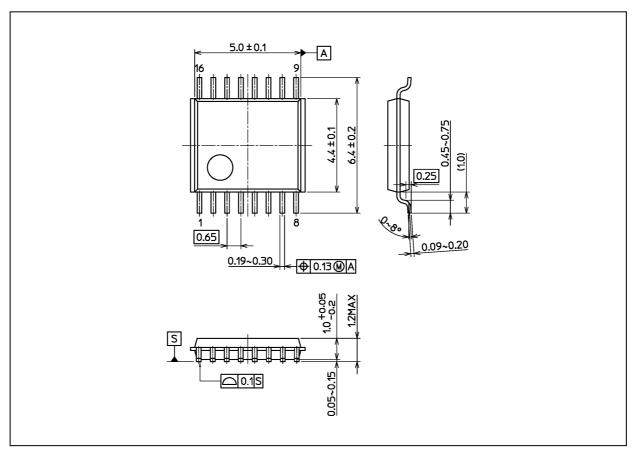


### 13. Input Equivalent Circuit



### **Package Dimensions**

Unit: mm



Weight: 0.055 g (typ.)

	Package Name(s)
Nickname: TSSOP16B	



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